

CSFA101-G Thru. CSFA105-G

Reverse Voltage: 50 to 600 Volts

Forward Current: 1.0 Amp

RoHS Device

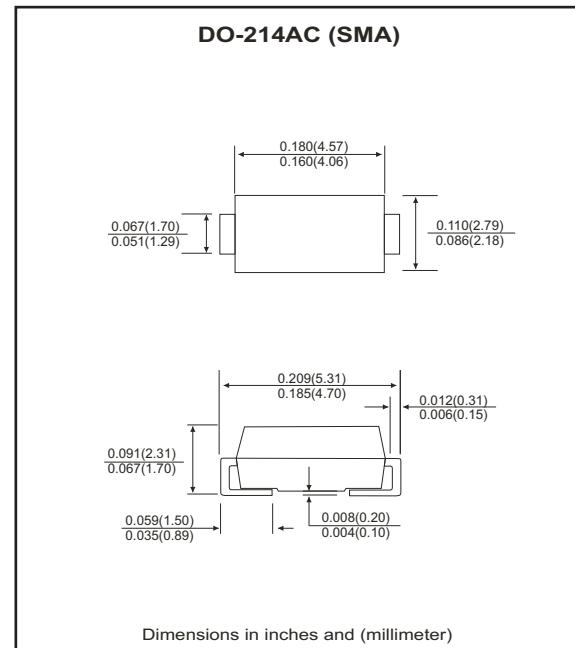


Features

- Ideal for surface mount applications.
- Easy pick and place.
- Plastic package has Underwriters Lab. flammability classification 94V-0.
- Super fast recovery time 35nS.
- Built-in strain relief.
- Low forward voltage drop.

Mechanical data

- Case: JEDEC DO-214AC, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Polarity: Color band denotes cathode end.
- Approx. weight: 0.063 grams



Maximum Ratings and Electrical Characteristics

Parameter	Symbol	CSFA101-G	CSFA102-G	CSFA103-G	CSFA104-G	CSFA105-G	Units
Max. repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	V
Max. DC blocking voltage	V _{DC}	50	100	200	400	600	V
Max. RMS voltage	V _{RMS}	35	70	140	280	420	V
Peak surge forward current, 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}			30			A
Max. average forward current	I _o			1.0			A
Max. instantaneous forward voltage @1.0A	V _F		0.95		1.25	1.5	V
Reverse recovery time	T _{rr}			35			nS
Max. DC reverse current at T _A =25°C rated DC blocking voltage T _A =100°C	I _R			5.0 100			µA
Max. thermal resistance (Note 1)	R _{θJL}			35			°C/W
Max. operating junction temperature	T _J			150			°C
Storage temperature	T _{STG}			-55 to +150			°C

Notes: 1. Thermal resistance from junction to lead mounted on P.C.B. with 8.0×8.0 mm copper pad area.

SMD Super Fast Recovery Rectifiers

Comchip
SMD Diode Specialist

RATING AND CHARACTERISTIC CURVES (CSFA101-G thru CSFA105-G)

Fig.1 Reverse Characteristics

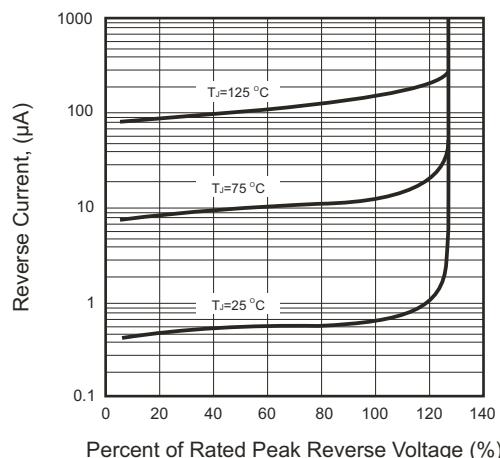


Fig.2 Forward Characteristics

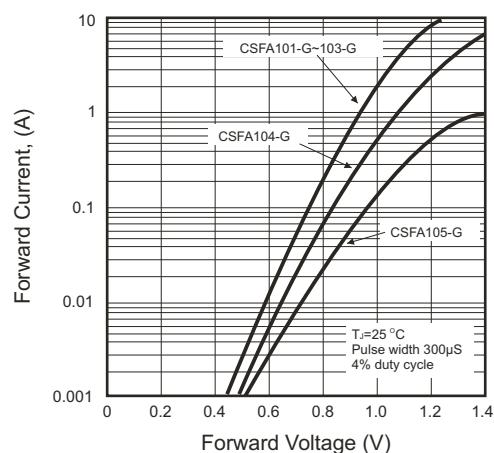


Fig.3 Junction Capacitance

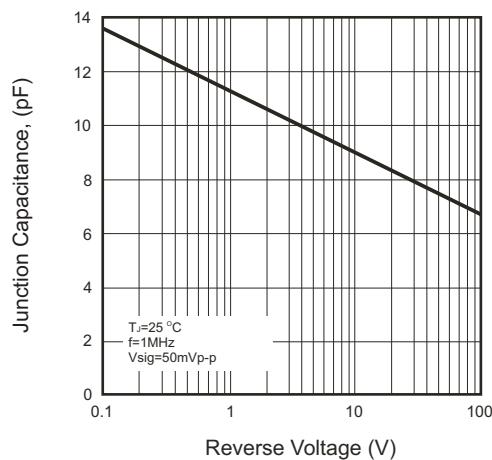


Fig.4 Non-repetitive Forward Surge Current

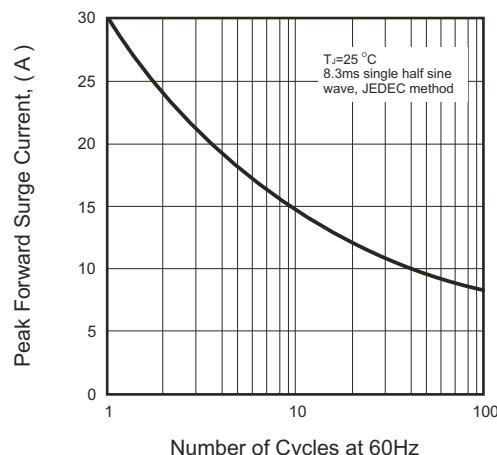


Fig.5 Test Circuit Diagram and Reverse Recovery Time Characteristics

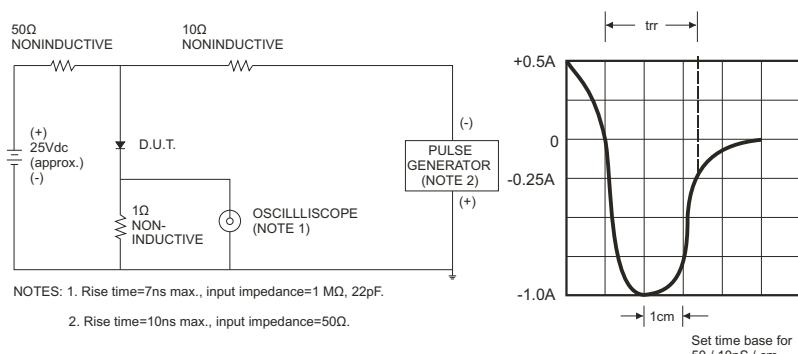


Fig.6 Current Derating Curve

